

BT136X-600D

Rev.01 - 16 April 2018

4Q Triac

Product data sheet

1. General description

Planar passivated very sensitive gate four quadrant triac in a SOT186A (TO-220F) plastic package intended for use in general purpose bidirectional switching and phase control applications, where high sensitivity is required in all four quadrants. This very sensitive gate "series D" triac is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

2. Features and benefits

- High blocking voltage capability
- Planar passivated for voltage ruggedness and reliability
- Very sensitive gate
- Triggering in all four quadrants
- Isolated package
- Direct triggering from low power drivers and logic ICs
- Low holding current for small load currents and lowest EMI at commutation

3. Applications

- General purpose motor control
- General purpose switching

4. Quick reference data

| 0 | Demonstern | O and the second | | N/- | | | 11 |
|--------------------------------------|--|--|--------|-----|-----|------|------|
| Symbol | Parameter | Conditions | Values | | | Unit | |
| Absolute | maximum rating | | | | | | |
| V_{DRM} | repetitive peak off-state voltage | | | 6 | 00 | | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _h ≤ 92 °C; <u>Fig. 1; Fig. 2</u> ; <u>Fig. 3</u> | 4 | | | A | |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u> | 25 | | A | | |
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
| Static ch | aracteristics | | | | | | |
| I _{GT} gate trigger current | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | | - | 2 | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | | - | 2.5 | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | | - | 2.5 | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u> | | - | 5 | 10 | mA |
| I _H | holding current | V _D = 12 V; T _i = 25 °C; <u>Fig. 9</u> | | - | 1.2 | 10 | mA |

5. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------------------|--------------------|----------------|
| 1 | T1 | main terminal 1 | mb | |
| 2 | T2 | main terminal 2 | | Ν |
| 3 | G | gate | | |
| mb | n.c. | mounting base; isolated | | sym051 |
| | | | | |
| | | | | |
| | | | ŲŲŲ | |
| | | | 1 2 3 | |

6. Ordering information

| Table 3. Ordering inform | nation | | |
|--------------------------|---------|--|---------|
| Type number | Package | | |
| | Name | Description | Version |
| BT136X-600D | TO-220F | plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack" | SOT186A |

7. Marking

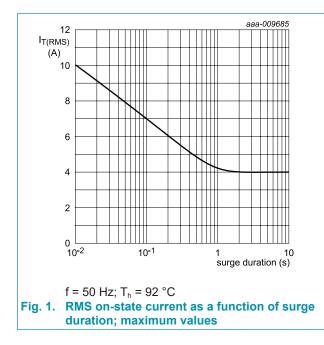
| Table 4 | . Marking codes | |
|---------|-----------------|---------------|
| Type r | number | Marking codes |
| BT136 | 3X-600D | BT136X-600D |

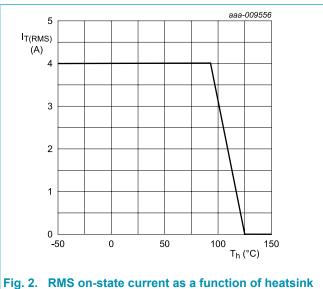
8. Limiting values

Table 5. Limiting values

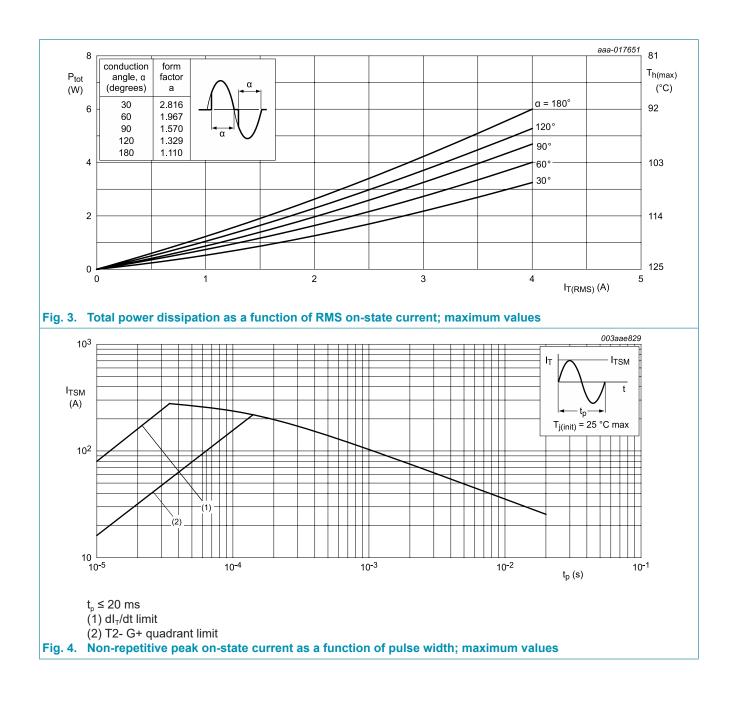
In accordance with the Absolute Maximum Rating System (IEC 60134).

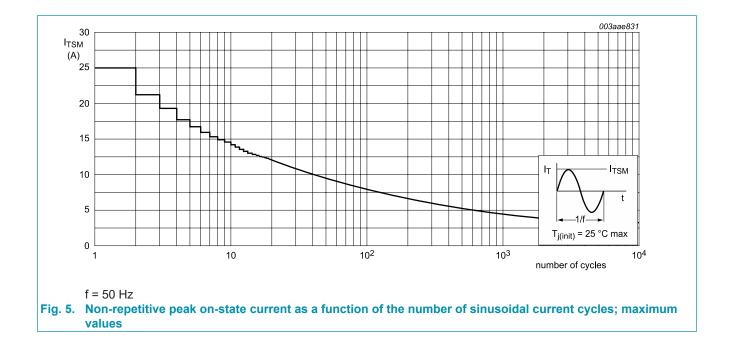
| Symbol | Parameter | Conditions | Values | Unit |
|--------------------------------|--|--|------------|------------------|
| V_{DRM} | repetitive peak off-state voltage | | 600 | V |
| $\mathbf{I}_{\mathrm{T(RMS)}}$ | RMS on-state current | full sine wave; $T_h \le 92 \text{ °C}$; Fig 1; Fig 2; Fig 3 | 4 | А |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig 4; Fig 5 | 25 | A |
| | | full sine wave; T _{j(init)} = 25 °C; t _p = 16.7 ms | 27 | А |
| l ² t | I ² t for fusing | t _P = 10 ms; SIN | 3.1 | A ² s |
| dl _⊤ /dt | rate of rise of on-state current | I _G = 10 mA; T2+ G+ | 50 | A/µs |
| | | I _G = 10 mA; T2+ G- | 50 | A/µs |
| | | I _G = 10 mA; T2- G- | 50 | A/µs |
| | | I _G = 20 mA; T2- G+ | 10 | A/µs |
| I _{GM} | peak gate current | | 2 | А |
| P _{GM} | peak gate power | | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | 0.5 | W |
| T _{stg} | storage temperature | | -40 to 150 | °C |
| T _j | junction temperature | | 125 | °C |





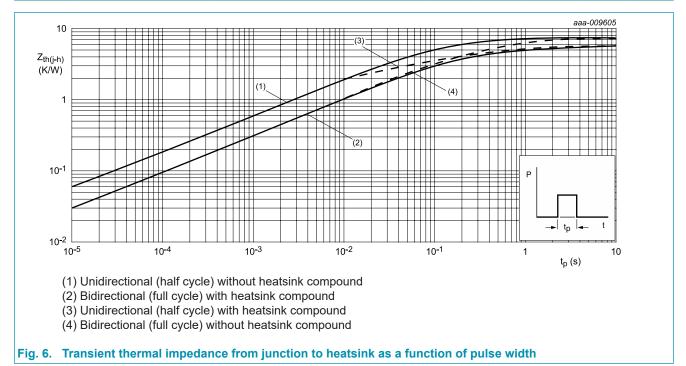
temperature; maximum values





9. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|---|---|-----|-----|-----|------|
| R _{th(j-h)} | thermal resistance from junction to | full or half cycle; with heatsink compound; Fig 6 | - | - | 5.5 | K/W |
| | heatsink | full or half cycle; without heatsink compound; <u>Fig 6</u> | - | - | 7.2 | K/W |
| $R_{\text{th(j-a)}}$ | thermal resistance from junction to ambient | in free air | - | 55 | - | K/W |

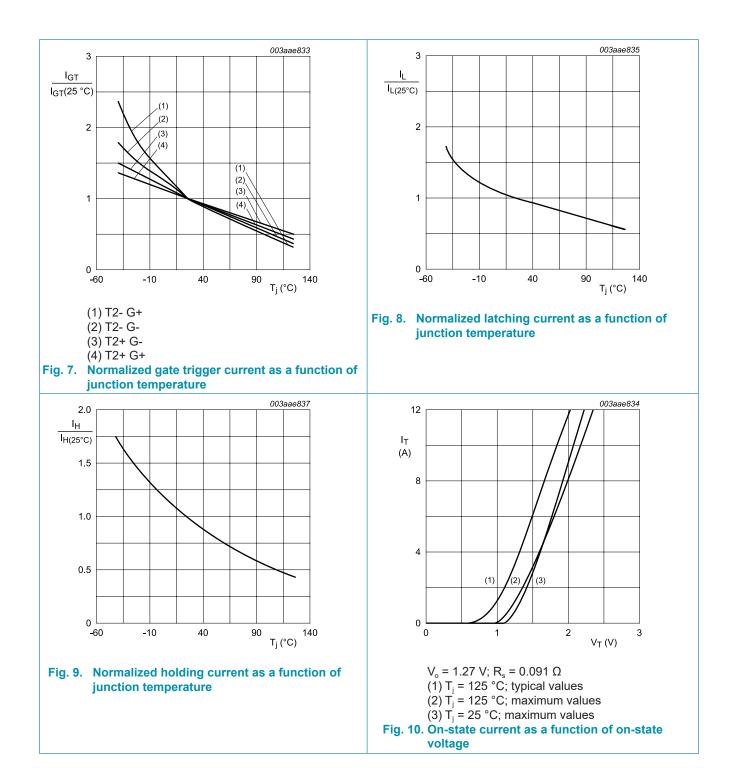


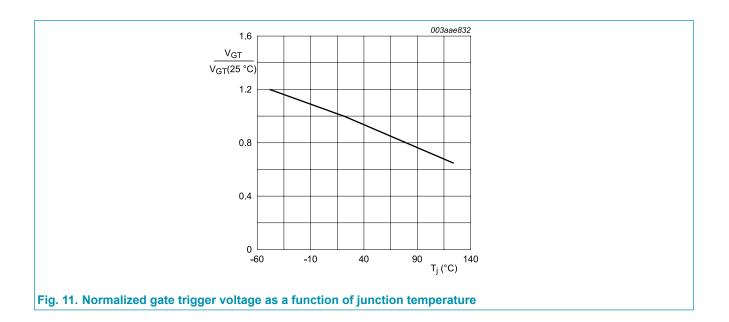
10. Isolation characteristics

| Table 7. Iso | lation characteristics | | | | | |
|------------------------|------------------------|---|-----|-----|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{isol(RMS)} | RMS isolation voltage | from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C | - | - | 2500 | V |
| C _{isol} | isolation capacitance | from main terminal 2 to external heatsink; f = 1 MHz; T_h = 25 °C | - | 10 | - | pF |

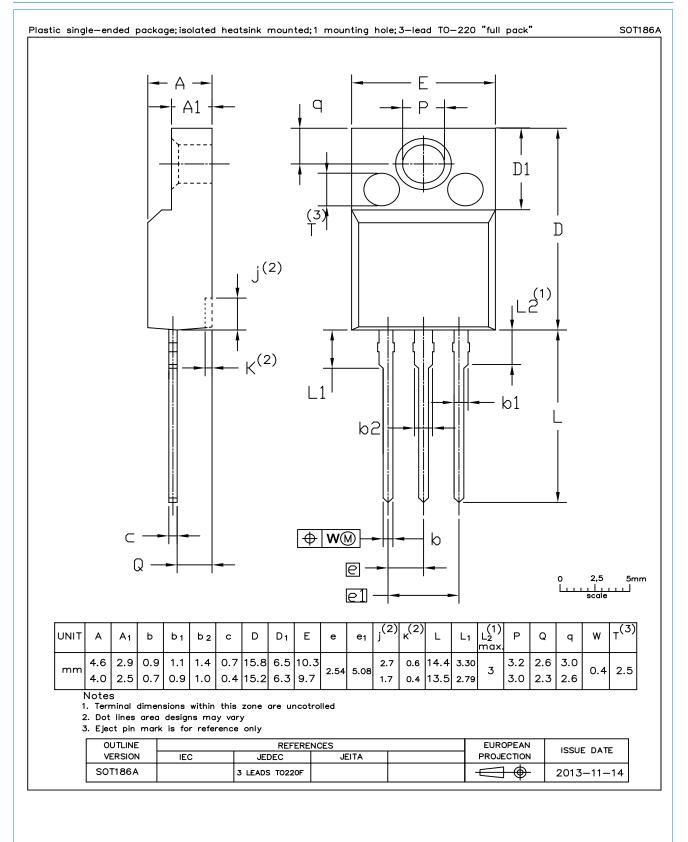
11. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|-----------------------------------|--|------|-----|-----|------|
| Static cha | aracteristics | | | | | |
| I _{GT} | gate trigger current | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 7 | - | 2 | 5 | mA |
| | | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 7 | - | 2.5 | 5 | mA |
| | | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 7 | - | 2.5 | 5 | mA |
| | | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; Fig. 7 | - | 5 | 10 | mA |
| L | latching current | $V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 8 | - | 1.6 | 10 | mA |
| | | V_{D} = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; Fig. 8 | - | 1.2 | 15 | mA |
| | | $V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 8 | - | 2.2 | 10 | mA |
| | | $V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; Fig. 8 | - | 1.2 | 15 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | 1.2 | 10 | mA |
| V _T | on-state voltage | I _T = 5 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.4 | 1.7 | V |
| V _{GT} | gate trigger voltage | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 11 | - | 0.7 | 1 | V |
| | | $V_{D} = 400 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 125 \text{ °C};$ Fig. 11 | 0.25 | 0.4 | - | V |
| I _D | off-state current | V _D = 600 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic | characteristics | | | | | _ |
| dV _D /dt | rate of rise of off-state voltage | $V_{DM} = 402 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; \text{ R}_{GK} = 1k\Omega;$ ($V_{DM} = 67\% \text{ of } V_{DRM}$); exponential waveform; gate open circuit | - | 5 | - | V/µs |
| t _{gt} | gate-controlled turn-on time | $V_{\rm D}$ = 600 V; I _{TM} = 6 A; I _G = 0.1 A; dI _G /dt = 5 A/µs | - | 2 | - | μs |
| | time | dI _G /dt = 5 A/µs | | | | |





12. Package outline



13. Legal information

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|--------------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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